

FS4VS-12

HIGH-SPEED SWITCHING USE

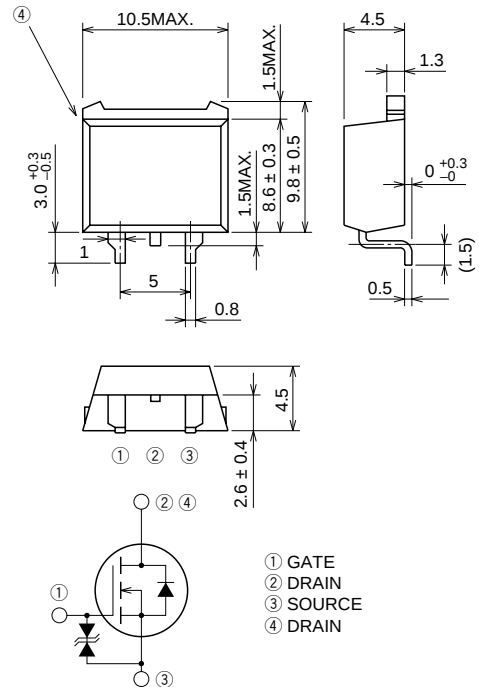
FS4VS-12



- V_{DSS} 600V
- r_{DS} (ON) (MAX) 2.6Ω
- I_D 4A

OUTLINE DRAWING

Dimensions in mm



TO-220S

APPLICATION

SMPS, DC-DC Converter, battery charger, power supply of printer, copier, HDD, FDD, TV, VCR, personal computer etc.

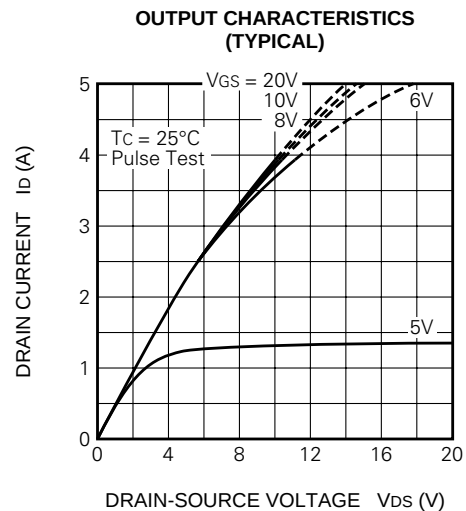
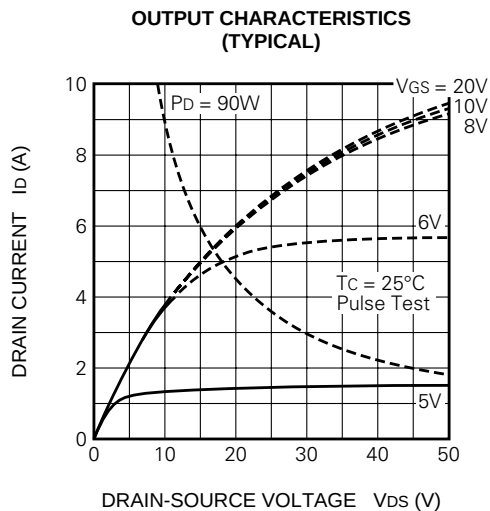
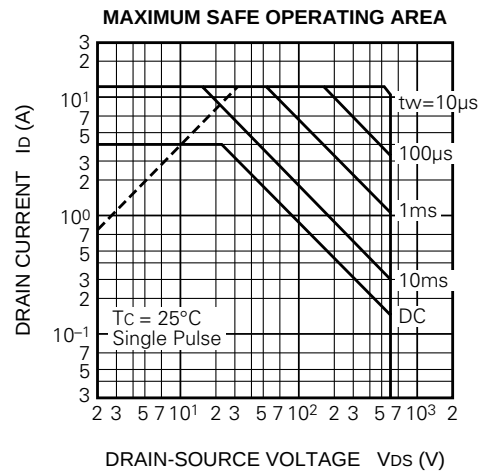
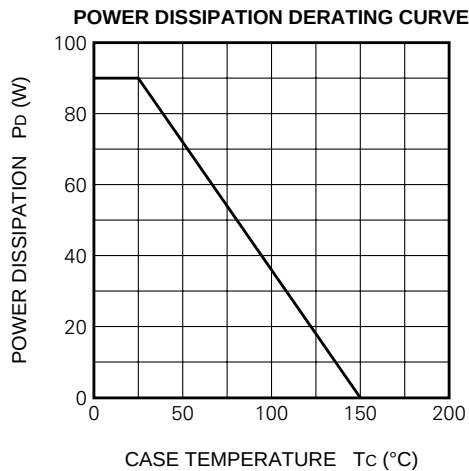
MAXIMUM RATINGS (T_c = 25°C)

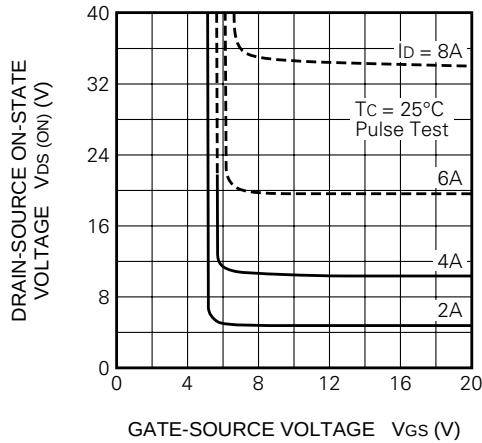
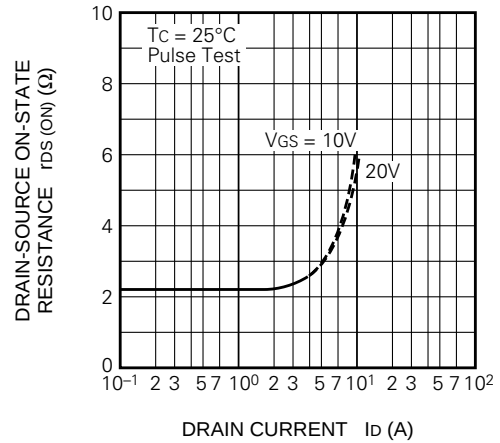
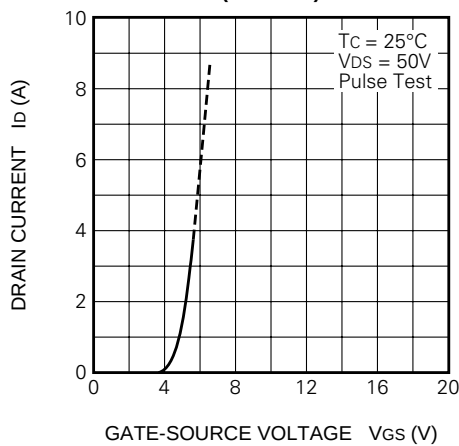
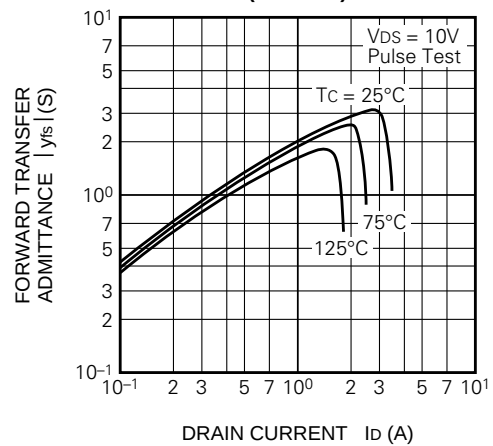
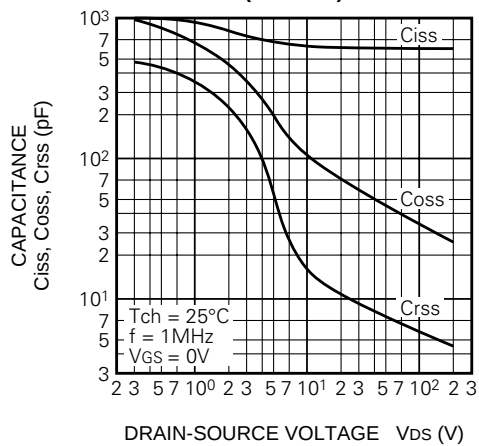
Symbol	Parameter	Conditions	Ratings	Unit
V _{DSS}	Drain-source voltage	V _{GS} = 0V	600	V
V _{GSS}	Gate-source voltage	V _{DS} = 0V	±30	V
I _D	Drain current		4	A
I _{DM}	Drain current (Pulsed)		12	A
P _D	Maximum power dissipation		90	W
T _{ch}	Channel temperature		-55 ~ +150	°C
T _{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	1.2	g

ELECTRICAL CHARACTERISTICS (T_{ch} = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	I _D = 1mA, V _{GS} = 0V	600	—	—	V
V (BR) GSS	Gate-source breakdown voltage	I _G = ±100μA, V _{DS} = 0V	±30	—	—	V
I _{GSS}	Gate-source leakage current	V _{GS} = ±25V, V _{DS} = 0V	—	—	±10	μA
I _{DSS}	Drain-source leakage current	V _{DS} = 600V, V _{GS} = 0V	—	—	1	mA
V _{GS} (th)	Gate-source threshold voltage	I _D = 1mA, V _{DS} = 10V	2	3	4	V
r _{DS} (ON)	Drain-source on-state resistance	I _D = 2A, V _{GS} = 10V	—	2.0	2.6	Ω
V _{DS} (ON)	Drain-source on-state voltage	I _D = 2A, V _{GS} = 10V	—	4.0	5.2	V
y _{fs}	Forward transfer admittance	I _D = 2A, V _{DS} = 10V	1.8	3.0	—	S
C _{iss}	Input capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	—	600	—	pF
C _{oss}	Output capacitance		—	65	—	pF
C _{rss}	Reverse transfer capacitance		—	10	—	pF
t _d (on)	Turn-on delay time	V _{DD} = 200V, I _D = 2A, V _{GS} = 10V, R _{GEN} = R _{GS} = 50Ω	—	15	—	ns
t _r	Rise time		—	15	—	ns
t _d (off)	Turn-off delay time		—	60	—	ns
t _f	Fall time		—	30	—	ns
V _{SD}	Source-drain voltage	I _S = 2A, V _{GS} = 0V	—	1.5	2.0	V
R _{th} (ch-c)	Thermal resistance	Channel to case	—	—	1.39	°C/W

PERFORMANCE CURVES



ON-STATE VOLTAGE VS.
GATE-SOURCE VOLTAGE
(TYPICAL)ON-STATE RESISTANCE VS.
DRAIN CURRENT
(TYPICAL)TRANSFER CHARACTERISTICS
(TYPICAL)FORWARD TRANSFER ADMITTANCE
VS. DRAIN CURRENT
(TYPICAL)CAPACITANCE VS.
DRAIN-SOURCE VOLTAGE
(TYPICAL)SWITCHING CHARACTERISTICS
(TYPICAL)